NSN 5962-01-279-0147

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View Online at https://aerobasegroup.com/nsn/5962-01-279-0147
Body Length:
Between 0.342 inches and 0.358 inches
Body Width:
Between 0.342 inches and 0.358 inches
Body Height:
Between 0.064 inches and 0.100 inches
Maximum Power Dissipation Rating:
300.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Programmable and monolithic and bipolar
Inclosure Material:
Ceramic
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
16 input
Case Outline Source And Designator:
C-2 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
12.0 volts power source
Time Rating Per Chacteristic:
75.00 nanoseconds propagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Pal
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 leadless
Shelf Life:
N/a
Unit Of Measure:
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No

Demilitarization:

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